

# HD74LS40 Dual 4-input Positive NAND Buffers

REJ03D0408-0200 Rev.2.00 Feb.18.2005

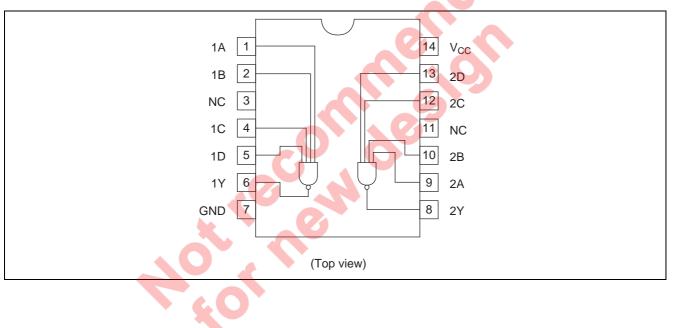
### Features

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS40FPEL	SOP-14 pin (JEITA)	PRSP0014DF-B (FP-14DAV)	FP	EL (2,000 pcs/reel)

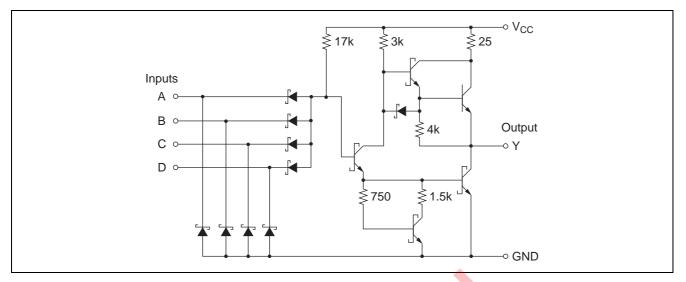
Note: Please consult the sales office for the above package availability.

### **Pin Arrangement**





## **Circuit Schematic (1/2)**



### Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	V <sub>cc</sub>	7	V
Input voltage	V <sub>IN</sub>	7	V
Power dissipation	PT	400	mW
Storage temperature	Tstg	-65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

### **Recommended Operating Conditions**

Item	Symbol	Min	Тур	Max	Unit
Supply voltage	V <sub>cc</sub>	4.75	5.00	5.25	V
Output ourroot	I <sub>OH</sub>	<b>S</b> –	—	-1.2	mA
Output current	I <sub>OL</sub>	—	—	24	mA
Operating temperature	Topr	-20	25	75	°C
4	0				

4



### **Electrical Characteristics**

 $(Ta = -20 \text{ to } +75 \ ^{\circ}\text{C})$ 

ltem	Symbol	min.	typ.*	max.	Unit	Condition
Input voltage	VIH	2.0	—	—	V	
Input voltage	VIL	_	—	0.8	V	
Output voltage	V <sub>OH</sub>	2.7	—	—	V	$V_{CC}$ = 4.75 V, $V_{IL}$ = 0.8 V, $I_{OH}$ = –1.2 mA
	V <sub>OL</sub>	_	—	0.5	V	$I_{OL} = 24 \text{ mA}$ $V_{CC} = 4.75 \text{ V}, \text{ V}_{IH} = 2 \text{ V}$
			—	0.4		$I_{OL} = 12 \text{ mA}$ $V_{CC} = 4.75 \text{ V}, \text{ V}_{H} = 2 \text{ V}$
Input current	I <sub>IH</sub>		—	20	μA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 2.7 \text{ V}$
	IIL		—	-0.4	mA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 0.4 \text{ V}$
	I,		—	0.1	mA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 7 \text{ V}$
Short-circuit output current	I <sub>OS</sub>	-30	_	-130	mA	V <sub>CC</sub> = 5.25 V
Supply current	I <sub>CCH</sub>	—	0.45	1.0	mA	V <sub>CC</sub> = 5.25 V
	ICCL		3	6	mA	V <sub>CC</sub> = 5.25 V
Input clamp voltage	Vıĸ			-1.5	V	$V_{CC} = 4.75 \text{ V}, \text{ I}_{IN} = -18 \text{ mA}$

Note:  $* V_{CC} = 5 V$ , Ta = 25°C

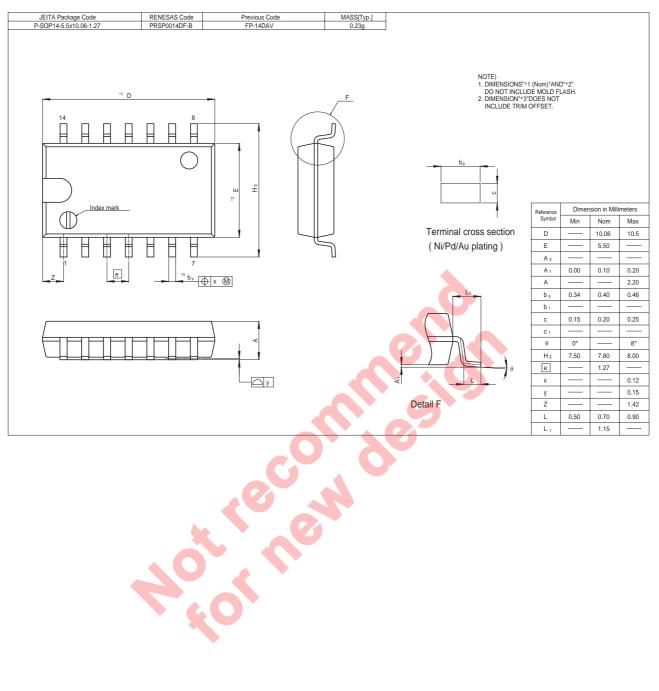
### **Switching Characteristics**

						$(V_{CC} = 5 V, Ta = 25^{\circ}C)$
ltem	Symbol	min.	typ.	max.	Unit	Condition
Propagation delay time	t <sub>PLH</sub>	—	12	24	ns	$C_{L} = 45 \text{ pF}, R_{L} = 667 \Omega$
Fropagation delay time	t <sub>PHL</sub>	—	12	24	ns	$O_{L} = 45 \text{ pr}$ , $N_{L} = 007 \text{ sz}$

Note: Refer to Test Circuit and Waveform of the Common Item "TTL Common Matter (Document No.: REJ27D0005-0100)".



### **Package Dimensions**





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